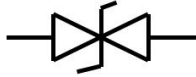
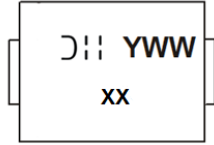
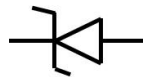
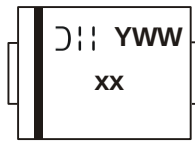


Marking Information

Bidirectional Device



Cathode Band for Unidirectional Device



xx = Product Type Marking Code (See Page 3)

D = Manufacturers' Marking

YWW = Date Code Marking

Y = Last Digit of Year (ex: 1 for 2021)

WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Pulse Power Dissipation (Non Repetitive Current Pulse Derated above T _A = +25°C) (Note 6)	P _{PK}	600	W
Peak Power Derating Above +25°C	P _{DER}	4.8	W/°C
Peak Forward Surge Current, 8.3ms Single Half Sine Wave Superimposed on Rated Load (Notes 6, 7 & 8)	I _{FSM}	100	A
Steady State Power Dissipation @ T _L = +75°C	PM _(AV)	5.0	W
Instantaneous Forward Voltage @ I _{PP} = 35A (Notes 6, 7 & 8)	V _F	3.5	V

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Operating Temperature Range	T _J	-55 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +175	°C

Notes:

6. Valid provided that terminals are kept at ambient temperature.

7. Measured with 8.3ms single half sine-wave. Duty cycle = 4 pulses per minute maximum.

8. Unidirectional units only.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Part Number Add C for Bi- Directional (Note 9)	Reverse Standoff Voltage V _{RWM} (V)	Breakdown Voltage V _{BR} @ I _T (Note 10)		Test Current I _T (mA)	Max. Reverse Leakage @ V _{RWM} (Note 12) I _R (μA)	Max. Clamping Voltage @ I _{PP} (Note 11) V _C (V)	Max. Peak Pulse Current I _{PP} (A)	Marking Code	
		Min (V)	Max (V)					BI-	UNI-
SMBJ7.0(C)AQ	7.0	7.78	8.95	10	200	12.0	50.0	AM	KM
SMBJ12(C)AQ	12.0	13.30	15.30	1.0	5.0	19.9	30.2	BE	LE
SMBJ14(C)AQ	14.0	15.60	17.90	1.0	5.0	23.2	25.8	BK	LK
SMBJ15(C)AQ	15.0	16.70	19.20	1.0	5.0	24.4	24.0	BM	LM
SMBJ16(C)AQ	16.0	17.80	20.50	1.0	5.0	26.0	23.1	BP	LP
SMBJ17(C)AQ	17.0	18.90	21.70	1.0	5.0	27.6	21.7	BR	LR
SMBJ18(C)AQ	18.0	20.00	23.30	1.0	5.0	29.2	20.5	BT	LT
SMBJ20(C)AQ	20.0	22.20	25.50	1.0	5.0	32.4	18.5	BV	LV
SMBJ22(C)AQ	22.0	24.40	28.00	1.0	5.0	35.5	16.9	BX	LX
SMBJ24(C)AQ	24.0	26.70	30.70	1.0	5.0	38.9	15.4	BZ	LZ
SMBJ26(C)AQ	26.0	28.90	33.20	1.0	5.0	42.1	14.2	CE	ME
SMBJ28(C)AQ	28.0	31.10	35.80	1.0	5.0	45.4	13.2	CG	MG
SMBJ30(C)AQ	30.0	33.30	38.30	1.0	5.0	48.4	12.4	CK	MK
SMBJ33(C)AQ	33.0	36.70	42.20	1.0	5.0	53.3	11.3	CM	MM
SMBJ36(C)AQ	36.0	40.00	46.00	1.0	5.0	58.1	10.3	CP	MP
SMBJ40(C)AQ	40.0	44.40	51.10	1.0	5.0	64.5	9.3	CR	MR
SMBJ51(C)AQ	51.0	56.70	65.20	1.0	5.0	82.4	7.3	CZ	MZ
SMBJ58(C)AQ	58.0	64.40	74.60	1.0	5.0	93.6	6.4	DG	NG
SMBJ70(C)AQ	70.0	77.80	89.50	1.0	5.0	113.0	5.3	DP	NP
SMBJ100(C)AQ	100.0	111.0	128.00	1.0	5.0	162.0	3.7	DZ	NZ

- Notes:
9. Suffix C denotes bidirectional device.
 10. V_{BR} measured with I_T current pulse = 10ms to 15ms.
 11. Per 10 × 1000μs waveform. See Figure 4.
 12. For Bi-Directional devices having V_{RWM} of 10V and under, the I_R is doubled.

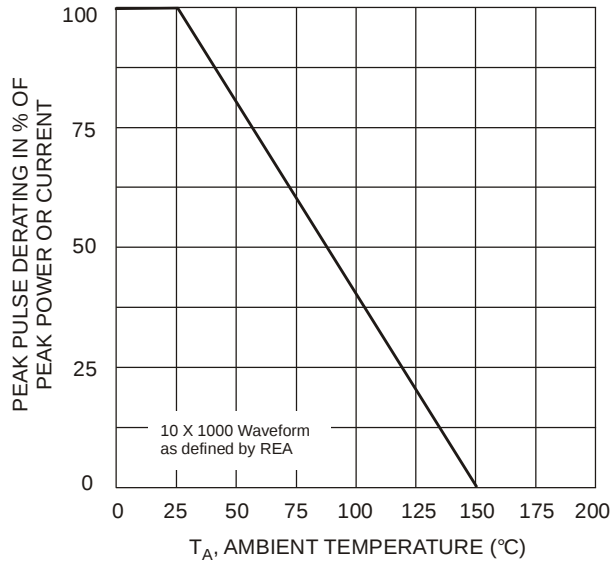


Fig. 1 Pulse Derating Curve

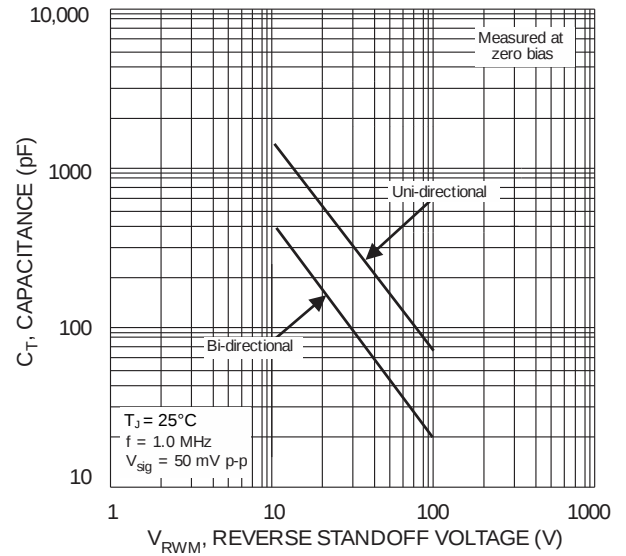


Fig. 2 Typical Total Capacitance

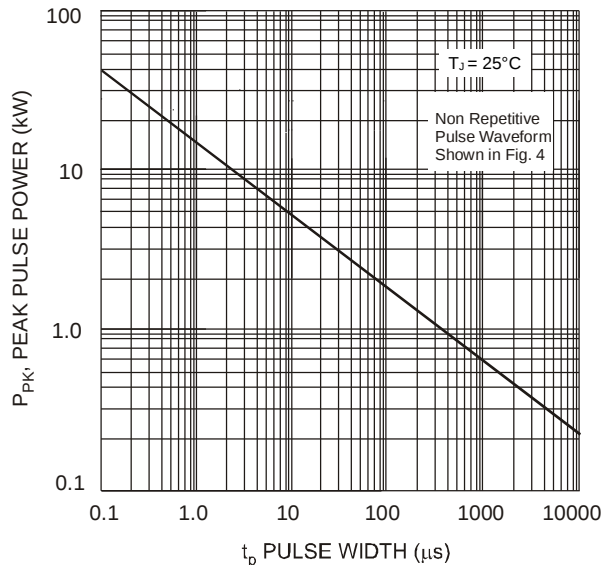


Fig. 3 Pulse Rating Curve

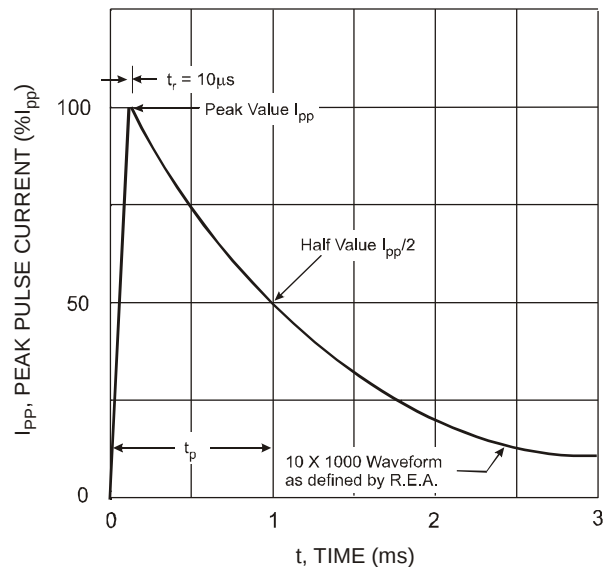


Fig. 4 Pulse Waveform

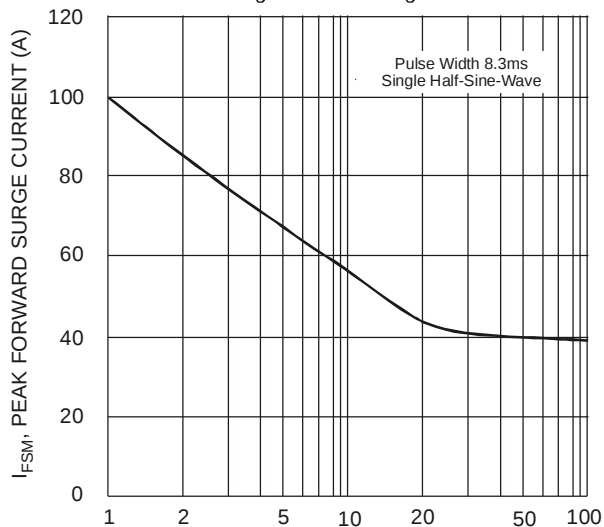


Fig. 5 Maximum Non-Repetitive Surge Current

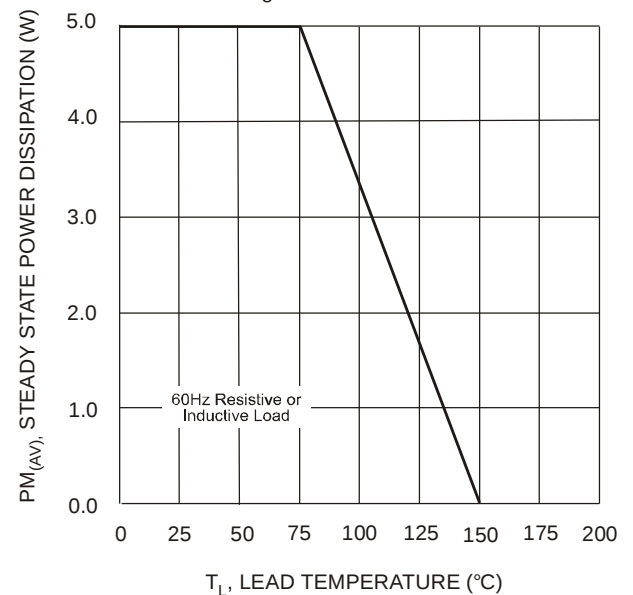
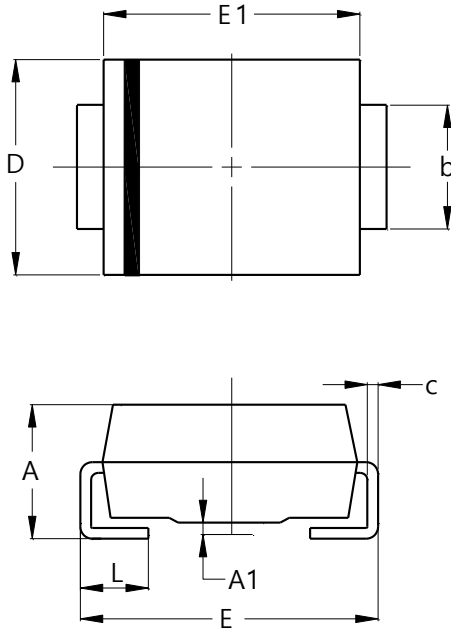


Fig. 6 Steady State Power Derating Curve

Package Outline Dimensions (Note 13)

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SMB



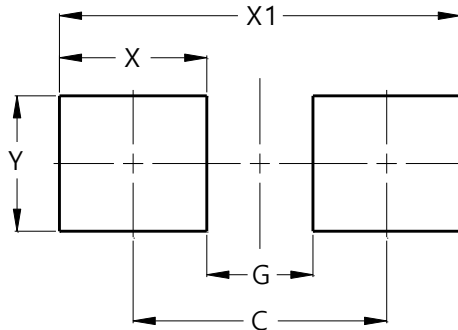
SMB		
Dim	Min	Max
A	2.00	2.50
A1	0.05	0.20
b	1.96	2.21
c	0.15	0.31
D	3.30	3.94
E	5.00	5.59
E1	4.06	4.57
L	0.76	1.52
All Dimensions in mm		

Note: 13. The bar in the upper drawing is polarity indicator for Cathode Band. It is for unidirectional devices only. Bidirectional devices have no polarity Indicator.

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SMB



Dimensions	Value (in mm)
C	4.30
G	1.80
X	2.50
X1	6.80
Y	2.30

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